

4 CHANNEL LOW CAPACITANCE TVS DIODE ARRAY
Product Summary

V_{BR} (min)	I_{PP} (max)	C_T (typ)
6V	4.7A	0.55pF

Description

The DT1446-04V is a high performance device suitable for protecting four high speed I/Os and one V_{CC} . These devices are assembled in SOT563 package. They have high ESD surge capability and low capacitance.

Applications

- Typically Used for High Speed Ports such as USB 2.0, IEEE1394, HDMI, Laptop and Personal Computers, Flat Panel Displays, Video Graphics Displays, SIM Ports

Features

- IEC 61000-4-2 (ESD): Air – $\pm 19kV$, Contact – $\pm 16kV$
- Low Channel Input Capacitance of 0.55pF Typical
- ESD Protection for four I/Os and one V_{CC}
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)**

Mechanical Data

- Case: SOT563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Copper leadframe (Lead Free Plating) Solderable per MIL-STD-202, Method208 Ⓔ3
- Weight: 0.003 grams (approximate)

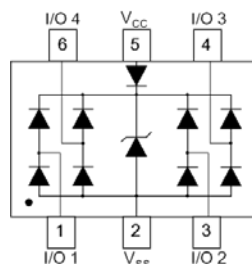
SOT563



Top View



Bottom View

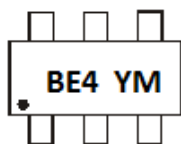


Device Schematic

Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DT1446-04V-7	Standard	BE4	7	8	3,000/Tape & Reel

- Notes:
- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 - See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 - For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information


BE4 = Product Type Marking Code
YM = Date Code Marking
Y = Year (ex: A = 2013)
M = Month (ex: 9 = September)

Date Code Key

Year	2013	2014	2015	2016	2017	2018
Code	A	B	C	D	E	F

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Current ,per IEC 61000-4-5	I _{PP_I/O}	4.7	A	I/O to V _{SS} , 8/20μs
Operating Voltage (DC)	V _{DC}	6	V	V _{CC} to V _{SS}
ESD Protection – Contact Discharge	V _{ESD_I/O}	±16	kV	I/O to V _{SS} , per IEC 61000-4-2
	V _{ESD_VCC}	±30	kV	V _{CC} to V _{SS} , per IEC 61000-4-2
ESD Protection – Air Discharge, per IEC 61000-4-2	V _{ESD_I/O}	±19	kV	I/O to V _{SS} , per IEC 61000-4-2
	V _{ESD_VCC}	±30	kV	V _{CC} to V _{SS} , per IEC 61000-4-2

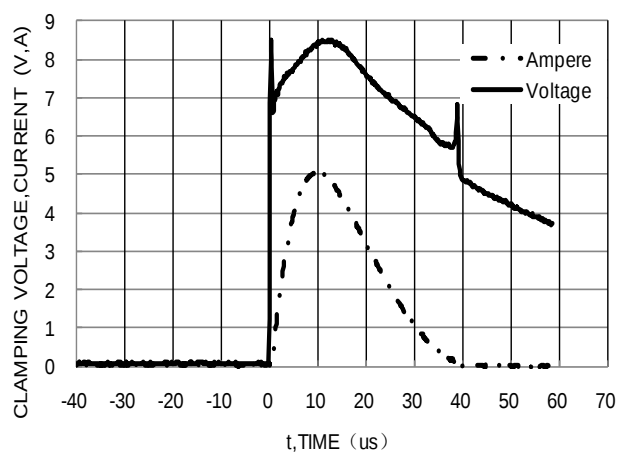
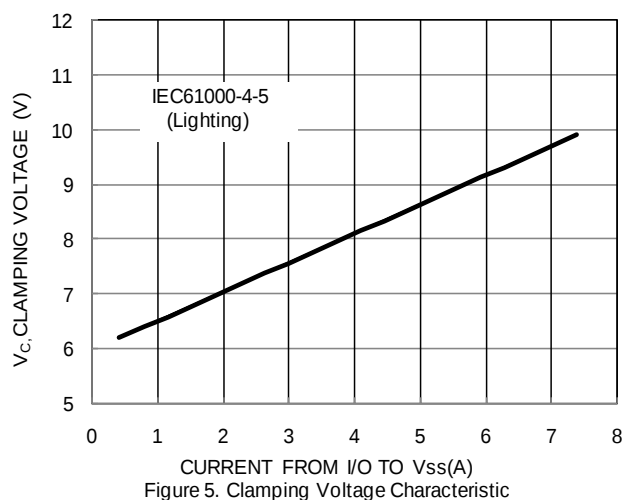
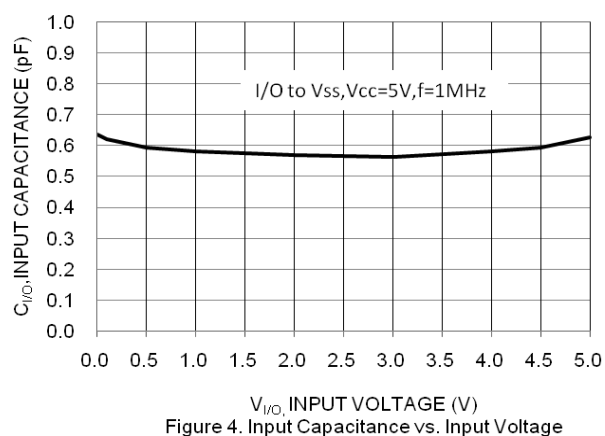
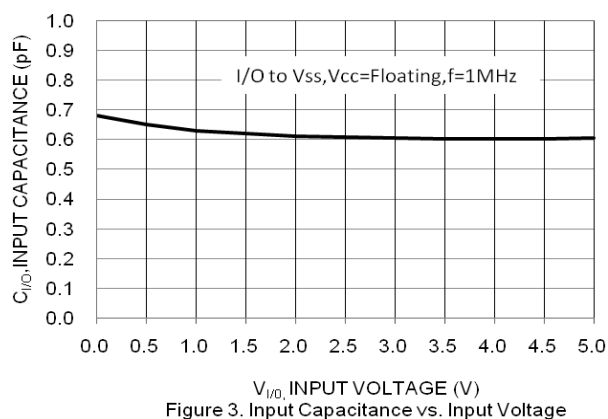
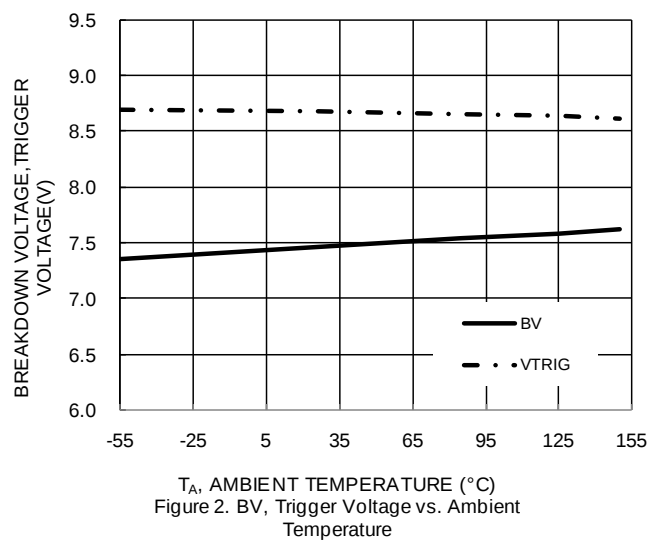
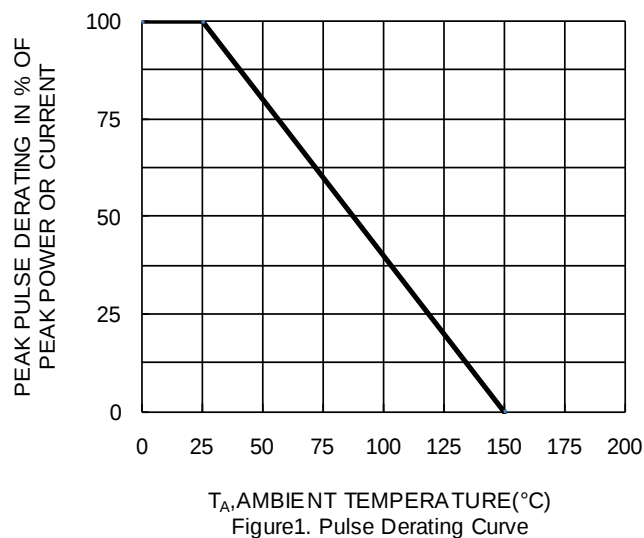
Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation Typical (Note 5)	P _D	380	mW
Thermal Resistance, Junction to Ambient Typical (Note 5)	R _{θJA}	327	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions
Reverse Working Voltage	V _{RWM}	—	—	5.5	V	V _{CC} to V _{SS}
Reverse Current (Note 6)	I _{R(VCC to VSS)}	—	—	5.0	μA	V _R = 5V, V _{CC} to V _{SS}
Reverse Current (Note 6)	I _{R(I/O to VSS)}	—	—	1.0	μA	V _R = 5V, any I/O to V _{SS}
Reverse Breakdown Voltage	V _{BR}	6.0	—	9.0	V	I _R = 1mA, V _{CC} to V _{SS}
Forward Clamping Voltage	V _F	—	0.8	1.0	V	I _F = 15mA, V _{SS} to V _{CC}
Reverse Clamping Voltage (Note 7)	V _{C_I/O}	—	8.5	—	V	I _{PP} = 4.7A, I/O to V _{SS} , 8/20μs
ESD Clamping Voltage	V _{ESD_VCC}	—	10	—	V	TLP, 20A, tp = 100 ns, V _{CC} to V _{SS}
	V _{ESD_I/O}	—	12	—	V	TLP, 20A, tp = 100 ns, I/O to V _{SS}
Dynamic Resistance	R _{DIF_VCC}	—	0.2	—	Ω	TLP, 20A, tp = 100 ns, V _{CC} to V _{SS}
	R _{DIF_I/O}	—	0.3	—	Ω	TLP, 20A, tp = 100 ns, I/O to V _{SS}
Channel Input Capacitance	C _{I/O to VSS}	—	0.55	0.65	pF	V _R = 2.5V, V _{CC} = 5V, f = 1MHz
Channel Input Capacitance	C _{I/O to VSS}	—	0.65	—	pF	V _R = 2.5V, V _{CC} = floating, f = 1MHz
Variation of Channel Input Capacitance	C _{I/OMAX-CI/OMIN}	—	0.03	—	pF	V _{CC} = 5V, V _{SS} = 0V, I/O = 2.5V, f = 1MHz, T = 25 °C, C _{I/OMAX-CI/OMIN}
Variation of Channel Input Capacitance	C _{I/OMAX-CI/OMIN}	—	0.05	—	pF	V _{CC} = floating, V _{SS} = 0V, I/O = 2.5V, f = 1MHz, T = +25°C, C _{I/OMAX-CI/OMIN}

- Notes:
- Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes, Inc. suggested pad layout AP02001, which can be found on our website at <http://www.diodes.com>.
 - Short duration pulse test used to minimize self-heating effect.
 - Clamping voltage value is based on an 8x20μs peak pulse current (I_{pp}) waveform.



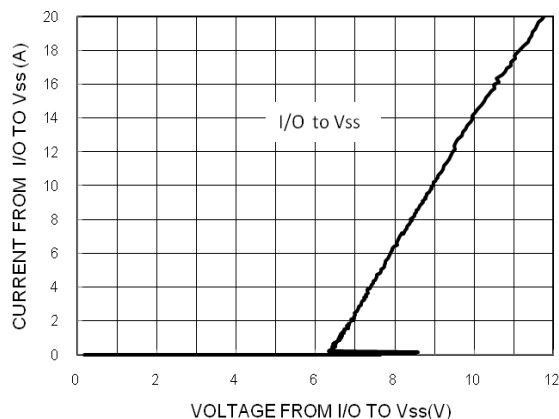


Figure 7. Transmission Line Pulsing (TLP) Measurement Current vs. Voltage

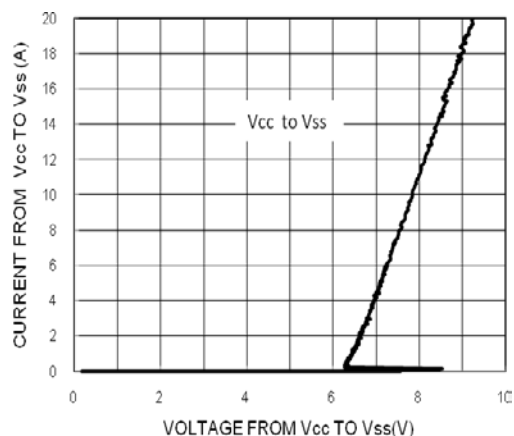
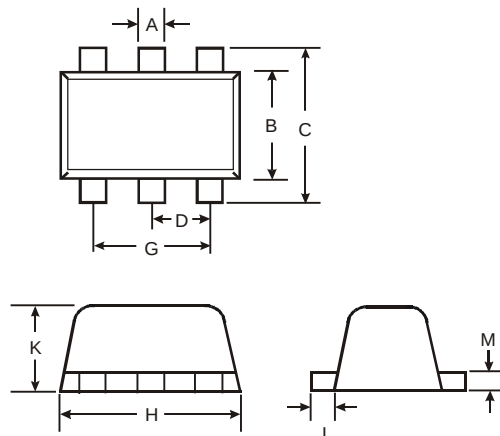


Figure 8. Transmission Line Pulsing (TLP) Measurement Current vs. Voltage

Package Outline Dimensions

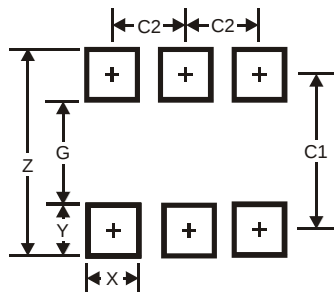
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



SOT563			
Dim	Min	Max	Typ
A	0.15	0.30	0.20
B	1.10	1.25	1.20
C	1.55	1.70	1.60
D	-	-	0.50
G	0.90	1.10	1.00
H	1.50	1.70	1.60
K	0.55	0.60	0.60
L	0.10	0.30	0.20
M	0.10	0.18	0.11
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	2.2
G	1.2
X	0.375
Y	0.5
C1	1.7
C2	0.5

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